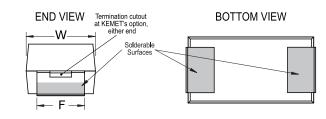


T493B336K006CT6220

T493 HRA, Tantalum, MnO2 Tantalum, HRA, 33 uF, 10%, 6.3 VDC, SMD, MnO2, Molded, DLA Drawing, C (0.01%/1000 Hrs), 600 mOhms, 3528, 2.1 mm, 0.8 mm



SIDE VIEW



General Information	
Series	T493 HRA
Dielectric	MnO2 Tantalum
Style	SMD Chip
Description	SMD, MnO2, Molded, DLA Drawing
RoHS	Yes
Termination	Tin
AEC-Q200	No
Typical Component Weight	102.3 mg

Click here for the 3D model.

Dimensions	
L	3.5mm +/-0.2mm
W	2.8mm +/-0.2mm
н	1.9mm +/-0.2mm
S	0.8mm +/-0.3mm
F	2.2mm +/-0.1mm

Packaging Specifications	
Packaging	T&R, 178mm
Packaging Quantity	2000

Specifications	
Capacitance	33 uF
Tolerance	10%
Voltage DC	6.3 VDC (85C), 4.22 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6% 120Hz 25C
Failure Rate	C (0.01%/1000 Hrs)
ESR	0.6 Ohms (100kHz 25C)
Ripple Current	354 mA (rms, 100kHz 25C)
Leakage Current	2.1 uA (5min 25°C)
Testing and Reliability	10 Cycles Surge Current Testing At +25C After Weibull

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